

# **Tuning Emission and Electron–Phonon Coupling in Lead-Free Halide Double** Perovskite Cs<sub>2</sub>AgBiCl<sub>6</sub> under Pressure

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S Supporting Information

ABSTRACT: Lead-free halide double perovskites have been proposed as candidates to replace Pb-halide perovskites in photovoltaic and optoelectronic applications due to their enhanced stability and nontoxicity. However, the limited understanding of the fundamental properties of halide double perovskites represents a hurdle to further improvement of their device performance. Our experimental studies demonstrate that the broad emission of Cs<sub>2</sub>AgBiCl<sub>6</sub> with a large Stokes shift stems primarily from exciton self-trapping owing to strong electron-phonon coupling. An unusual blue shift of the emission accompanied by a red shift of the absorption edge occurred due to the reduced lattice relaxation energy upon lattice compression in the cubic phase. Electronphonon coupling reduction is critical to the enhancement of photoluminescence intensity and tuning emission range in



Cs<sub>2</sub>AgBiCl<sub>6</sub> under high pressure. The structure-property relationships illuminated by our work can provide the basis for improving the performance of halide double perovskites.

ue to their excellent properties including strong light absorption, long carrier diffusion lengths and lifetimes, high charge carrier mobility, suitable band gap, etc.,<sup>1–3</sup> metal halide perovskites have attracted considerable attention from the clean energy sector for future photovoltaic and optoelectronic applications. Despite the performance and exciting potential of Pb-based perovskites, the environmental impact and toxicity of Pb and the inherent instability of the pristine materials with respect to moisture, heat, oxygen, and light are still primary concerns that severely limit their commercialization and the widespread use of this new technology.4,5

Substantial efforts have been invested in the search for lowtoxicity and stable halide perovskites with photovoltaic and photoelectric properties that are comparable to those of Pbbased perovskites. Recently, Bi-based halide double perovskites Cs<sub>2</sub>AgBiX<sub>6</sub> (Br, Cl) have been proposed and synthesized as promising alternatives. These perovskites possess three-dimensional (3D) cubic structures with corner-sharing metal halide octahedra and considerable flexibility for compositional adjustments.<sup>6-10</sup> Halide double perovskites exhibit great potential for a multitude of other applications, such as photodetectors, X-ray detectors, photocatalysts, light-emitting diodes (LEDs), etc.<sup>11-14</sup> Even though numerous investigations have been performed to improve device performance, the optimized PCE of halide double perovskite photovoltaic devices (<2.5%) is still lower than that of the Pb-based perovskite analogues,<sup>15–17</sup> implying inherent electronic limitations and differences compared to Pb-containing materials. Strong electron-phonon coupling is found in halide double perovskite,<sup>18,19</sup> which increases carrier scattering and reduces charge carrier mobility, low photoluminescence (PL) quantum yield, and undesirable electron-hole recombination.<sup>8,20,21</sup>

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Whether the emission mechanisms of halide double perovskites stem from indirect transitions, defects, or exciton selftrapping remains a subject of debate.<sup>18,22,23</sup> Various strategies are needed to further understand and modify their electronic structures and relevant properties, including the band gap, electron–phonon interactions, the emission mechanism, and the electric transport of halide double perovskites.<sup>24</sup>

The atomic-level understanding of structure-property relationships can provide crucial insight into materials development and improved performance. High-pressure technology is a powerful tool for modifying the lattice structures and electronic wave functions of materials, which in turn alters their various physical/chemical properties without changing chemistry.<sup>25</sup> In recent years, high-pressure studies on conventional halide perovskites (ABX<sub>3</sub>) have been conducted to improve their photovoltaic properties and reveal novel phenomena, including band gap narrowing, carrier lifetime increase, PL enhancement, resistance reduction, etc.<sup>26-32</sup> Band gap narrowing and an increase in carrier lifetime in methylammonium lead iodide (MAPbI<sub>3</sub>) can occur simultaneously under mild pressure (<0.3 GPa), which is promising for practical applications. Under higher pressure, the metallization of MAPbI<sub>3</sub> by band gap closure was confirmed above 60 GPa, indicateing a wholly new electronic structure and transport properties.<sup>33</sup> The partially retained band gap narrowing of the pressure-treated 2D hybrid perovskite  $(C_4H_9NH_3)_2(CH_3NH_3)_{n-1}Pb_nI_{3n+1}$  and 3D halide double perovskite Cs<sub>2</sub>AgBiBr<sub>6</sub> by achieving metastable states offers a practical approach to tailor their optoelectronic properties for improved light absorbers.34,35

Here, we systematically studied the optical, electrical, and structural properties of  $Cs_2AgBiCl_6$  with applied pressure up to 31 GPa at room temperature by conducting in situ highpressure PL, UV–vis absorption, X-ray diffraction, Raman, and resistance experiments. We confirmed that the broad emission of  $Cs_2AgBiCl_6$  mainly originates from exciton self-trapping. A negative shift of PL relative to the absorption edge was observed due to the decreased lattice relaxation energy upon compression. Bond length compression remarkably reduced electron–phonon coupling and suppressed ionic transport in the cubic phase of  $Cs_2AgBiCl_6$ . This work not only reveals the structure–property relationships in halide double perovskites but also clarifies potential engineering routes for considerably modifying the crystal structures and various properties of halide double perovskite with better materials by design.

Pressure effects on optical properties, including the band gap and emission by tuning the bond length and bond angle in crystals, are of great concern to us for photovoltaic or optoelectronic applications. To determine how the band gap of Cs<sub>2</sub>AgBiCl<sub>6</sub> changes with compression, we performed in situ high-pressure UV-vis absorption measurements up to ca. 31 GPa (Figure 1). Cs<sub>2</sub>AgBiCl<sub>6</sub> displayed a sharp increase in absorption below 440 nm with a gentle absorption tail at ambient conditions, suggesting indirect band gap character, which is consistent with previous experimental and theoretical reports.<sup>23</sup> The band gap of Cs<sub>2</sub>AgBiCl<sub>6</sub> was estimated by extrapolating the linear portion of the  $(\alpha dh\nu)^{1/2}$  versus  $h\nu$  in indirect band gap Tauc plots, where  $\alpha$  is the absorption coefficient, d is the sample thickness, and  $h\nu$  is the photon energy (Figure 1b). The pressure-driven band gap evolution of Cs<sub>2</sub>AgBiCl<sub>6</sub> upon compression is shown in Figure 1c. As pressure increases, the band gap of Cs<sub>2</sub>AgBiCl<sub>6</sub> gradually red shifts below 5 GPa, followed by a sharp increase above 5 GPa



Figure 1. (a) Absorption spectra of  $Cs_2AgBiCl_6$  as a function of pressure. The arrows trace the evolution of the absorption edge. (b) Indirect band gap Tauc plot for  $Cs_2AgBiCl_6$  at ambient pressure. (c) Band gap evolution of  $Cs_2AgBiCl_6$  as a function of pressure.

over a small pressure region. With the further increase of pressure above 7 GPa, a red shift in the band gap is observed. When the applied pressure reaches approximately 14 GPa, the band gap is nearly unchanged until ca. 31 GPa. During decompression, the absorption spectra of  $Cs_2AgBiCl_6$  maintain a blue shift above 0.8 GPa. When the pressure is released completely, the absorption spectra of pressure-treated samples show a slight difference compared with its initial state (Figure S1).

We carried out in situ high-pressure PL experiments to explore the light emission behavior of Cs<sub>2</sub>AgBiCl<sub>6</sub> as a function of pressure (Figure 2). Under ambient pressure, Cs<sub>2</sub>AgBiCl<sub>6</sub> exhibits a broad orange emission with a peak centered at 648 nm and a full width at half-maximum (fwhm) of 186 nm, suggesting a very large Stokes shift of 265 nm (Figures 2b and S2). As the pressure increases, the PL peak evidently blue shifts along with the PL peak position from an initial 648 to 532 nm at 5.1 GPa and then slowly red shifts (Figure 2c), corresponding to a change of carrier lifetime from a continuous decrease to slow increase (Figures S3 and S4). Meanwhile, the corresponding fwhm of the PL spectrum shows a remarkable decrease before 5.1 GPa, followed by widening upon further compression (Figure 2d). The dramatic behavior of the negative shift of the PL peak toward higher energy relative to the absorption edge is distinctly different from the reported high-pressure studies of conventional Pb-based halide perovskites with a direct transition, implying a different electronic transition mechanism rather than the multiple indirect transitions. Initially, the PL intensity of Cs<sub>2</sub>AgBiCl<sub>6</sub> increases gradually for pressure below 1 GPa. This occurrence is followed by a progressive decrease in PL until it completely disappears at approximately 8 GPa (Figure 2e). Upon decompression, the PL spectra return to the original profile and position, but the PL intensity is weaker than that of its initial state (Figure S5). This abnormal phenomenon can be reproduced in our repeated experiments. The considerable



Figure 2. (a) PL micrographs upon compression. (b) PL spectra of  $Cs_2AgBiCl_6$  as a function of pressure during compression. (c) PL peak location of  $Cs_2AgBiCl_6$  against pressures. (d) Fwhm of  $Cs_2AgBiCl_6$  as a function of pressure. (e) Evolution of PL intensity as a function of pressure. (f) Pressure-dependent chromaticity coordinates of the emissions.



Figure 3. High-pressure synchrotron XRD patterns for Cs<sub>2</sub>AgBiCl<sub>6</sub>. Black asterisks mark the appearance of new diffraction peaks. (b) Rietveld refinement of XRD patterns of Cs<sub>2</sub>AgBiCl<sub>6</sub> at 1 atm and 5.6 GPa. The insets show the corresponding crystal structure. Cs: dark green ball; Ag: gray ball; Bi: purple ball; Cl: light green ball.

tunability of the PL position, the fwhm, and the intensity for pressure-driven emission spectra indicate continuous changes in the color of light emission with pressure, which can be clearly observed in PL optical images (Figure 2a). Furthermore, we recorded pressure-dependent CIE chromaticity coordinates of emission from  $Cs_2AgBiCl_6$  (Figure 2f and

Table S1). The evolution of the CIE chromaticity coordinates is continuous from ambient pressure (0.54, 0.44) to 4.8 GPa (0.34, 0.52), corresponding to color transformation from original orange to green-enriched white. The ability to alter emission intensity and chromaticity by high-pressure technologies indicates a prospective strategy for optimizing LED

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design with varying chromaticity for multifunctional applications by using strain/pressure engineering with reasonable chemical regulation or device construction.

The optical properties of Cs<sub>2</sub>AgBiCl<sub>6</sub> strongly depend on the pressure response of the inorganic lattice framework. To better understand the root cause of the abnormal PL and band gap evolution, we carried out in situ synchrotron high-pressure XRD experiments on Cs<sub>2</sub>AgBiCl<sub>6</sub> up to ca. 31 GPa at room temperature. Figure 3a shows a series of pressure-dependent XRD patterns. With increasing pressure, the diffraction peaks shift continuously toward smaller *d*-spacing due to lattice compression. At 5.6 GPa, the subtle splitting of two diffraction peaks located at around 6.8 and 13.7° indicates a pressureinduced phase transition,<sup>36</sup> accompanied by the dramatic broadening and weakening of the diffraction peaks with further compression, which should be associated with the deviatoric stress and a transition-induced breakdown of the sample grains originating from the nonhydrostatic conditions according to the previous high-pressure studies.<sup>37,38</sup> As the pressure is increased to 13.8 GPa, significant structural distortion occurs, as evidenced by the disappearance and broadening of partial diffraction peaks, as well as appearance of a broad diffraction background, suggesting the beginning of amorphization and the increased disorder of AgCl<sub>6</sub> and BiCl<sub>6</sub> octahedra.<sup>39,40</sup> Finally, a complete amorphous phase is observed at around 31 GPa with the disappearance of all sharp diffraction peaks and the presence of only two weak broad bands, indicating a loose long-range order in the crystal structure. During decompression, the amorphous state is preserved before 1.2 GPa, which is obviously lower compared with the onset pressure for amorphization (Figure S6). Finally, Cs<sub>2</sub>AgBiCl<sub>6</sub> restores to the original cubic phase, but the XRD patterns of pressure-treated samples are broadened and weakened along with the disappearance of partially small diffraction peaks. These findings imply that the crystallinity is not reversible completely after decompression, which should be responsible for changes in optical properties of the pressure-treated samples.

Rietveld refinement was conducted to determine how the crystal structure of Cs<sub>2</sub>AgBiCl<sub>6</sub> changes with pressure (Figure 3b). At ambient conditions, Cs<sub>2</sub>AgBiCl<sub>6</sub> possesses a cubic structure with the space group Fm-3m and lattice parameters a = 10.785(5) Å and V = 1254.470(4) Å<sup>3</sup>, in good agreement with previous literature reports.<sup>7</sup> This double perovskite structure is a network of 3D corner-sharing octahedra, where alternating AgCl<sub>6</sub> and BiCl<sub>6</sub> octahedra are arranged in a rocksalt configuration with Cs atoms occupying the cubic octahedron cavity. The Ag-Cl bond lengths are slightly longer than that of the Bi-Cl bond due to Cl atoms having a small displacement toward Bi atoms. For the 5.6 GPa pattern, a tetragonal structure with the space group I4/m was adopted to fit two split diffraction peaks. I4/m is a subgroup of Fm-3m, allowing BiCl<sub>6</sub> and AgCl<sub>6</sub> octahedra coherent rotation with an opposite direction along the *c* axis in the *ab* plane. The rotation angle  $\theta$  of the octahedra in the tetragonal phase is about 7.4°, while the Bi-Cl-Ag bond along the c axis remains  $180^{\circ}$ (Figure S7). In addition, BiCl<sub>6</sub> and AgCl<sub>6</sub> octahedra are slightly distorted with different Bi(Ag)-Cl bond lengths in the *ab* plane compared with along the *c* axis. Therefore, the cubictetragonal transition is primarily dominated by the torsional rotation of BiCl<sub>6</sub> and AgCl<sub>6</sub> octahedra along the c axis with negligible deformation of the BiCl<sub>6</sub> and AgCl<sub>6</sub> octahedra. The discontinuous cell parameters and volume changes are

consistent with optical properties and structural transitions upon compression (Figure S8).

The local lattice vibrations of  $Cs_2AgBiCl_6$  are affected by the changes of the inorganic octahedra under pressure; thus, we conducted in situ high-pressure Raman experiments. As shown in Figure 4, we observed three vibrational modes below 360



Figure 4. Raman spectra of Cs<sub>2</sub>AgBiCl<sub>6</sub> as a function of pressure. Black asterisks mark the appearance of new peaks.

cm<sup>-1</sup> at ambient conditions. According to the assignment of analogues in previous studies, the band at 115 cm<sup>-1</sup> is ascribed to a breathing vibration of the Ag-Cl bonds with T<sub>2g</sub> symmetry, while the two bands at 212 and 284 cm<sup>-1</sup> belong to the stretching vibrations of the AgCl<sub>6</sub> octahedron with different vibrational symmetries of Eg and Alg, respectively.<sup>18,19</sup> With increasing pressure, all bands shift to higher frequency owing to the AgCl<sub>6</sub> octahedron shrink. As pressure increases to 5.1 GPa, the splitting of the Ag-Cl breathing vibration illustrates the occurrence of a phase transition associated with inorganic octahedron rotation. At above 13.6 GPa, the progressive amorphization of Cs2AgBiCl6 is observed with the broadening, weakening, and eventual disappearance of the vibrational mode. Upon decompression, all of the Raman shifts are reversible, but the intensity of the vibration mode is relatively weaker than its initial state (Figure S9). Those changes in Raman spectra are consistent with the XRD results.

Electrical conductivity of metal halide double perovskites is a key parameter for their optoelectronic or photovoltaic applications. To track the pressure response on electrical properties of  $Cs_2AgBiCl_6$ , we implemented in situ resistance experiments upon compression. As shown in Figure S10,  $Cs_2AgBiCl_6$  with ionic conduction exhibits poor conductivity, as evidenced by a large resistance. As the pressure increases, the resistance increases continuously before ca. 6 GPa, suggesting that the ionic migration is suppressed due to the reduction of the ionic migration channels along with lattice shrinkage and interstitial spaces reduction.<sup>41,42</sup> Within the tetragonal phase of  $Cs_2AgBiCl_6$ , the torsional rotations of BiCl<sub>6</sub> and  $AgCl_6$  octahedra improve the ionic migration channels,



Figure 5. Schematic illustrations of emission evolutions at ambient conditions (a) and high pressure (b) in the cubic phase. Ground state (GS), free-carrier state (FC), free-exciton state (FE), and various self-trapped exciton states (STE), B = half-width of the exciton band,  $E_{LR}$  = lattice relaxation energy,  $E_{a,trap}$  = activation energy for self-trapping, and  $E_{a,detrap}$  = activation energy for detrapping.

which decreases resistance. Under higher pressure, the resistance is almost constant, corresponding to a pressure-induced amorphous phase.

The Fröhlich interactions from the coupling of longitudinal optical (LO) phonons and lattice vibrations are significant scattering mechanisms in polar semiconductors. The A<sub>1g</sub> LO phonon mode of Cs<sub>2</sub>AgBiCl<sub>6</sub> has an energy of  $\hbar\omega_{LO} = 284$  $cm^{-1}$  at ambient conditions. The Huang–Rhys parameter S, as an indicator of the electron-phonon coupling strength, allows us to describe the equilibrium position offset between the excited and ground states, as well as the microscopic details of vibration coupling.43 We can estimate the Huang-Rhys parameters according to the measured Stokes shift energy  $E_{\text{Stokes}}$  and the LO phonon mode energy according to the relationship  $E_{\text{Stokes}} = 2S\hbar\omega_{\text{LO}}$ . At ambient conditions, we obtained a large Huang-Rhys parameter of 18.1, which is slightly larger than the value of the analogues, Cs<sub>2</sub>AgBiBr<sub>6</sub>, which exhibits giant electron-phonon coupling (S = 15.4), indicating a relatively stronger electron-phonon coupling via Fröhlich interaction in the Cs<sub>2</sub>AgBiCl<sub>6</sub> crystal. As the pressure increases, the  $E_{\text{Stokes}}$  decreases gradually, as evidenced by a negative shift of emission, as well as a continuous increase in the LO phonon mode energy. Therefore, the Huang-Rhys parameter decreases as a function of pressure, yielding a small value of about 8.5 at 4.5 GPa (Figure S11). This result shows that the electron-phonon coupling can be considerably reduced by lattice compression in the cubic phase.

Our mechanistic studies indicate that the broad emission of Cs<sub>2</sub>AgBiCl<sub>6</sub> is primarily a result of exciton self-trapping due to strong coupling between the exciton and lattice. In addition, previous reports that self-trapped exciton (STE) emission in binary alkali halides shifts inversely with respect to the absorption edge upon compression is consistent with our emission mechanism.<sup>44–47</sup> The Jahn–Teller distortion, B-site metal disordering associated with the antisite defects [BiAg (Bion-Ag) and Ag<sub>Bi</sub> (Ag-on-Bi)], and a low electronic dimensionality are responsible for STE formation, which can result in localization through elastic lattice distortions and plays an important role in enhancing electron-phonon coupling.<sup>13,18,48</sup> Therefore, the stabilized and distorted excited trap states with a distribution of energy level relative to the ground state leads to a broad emission with a relatively large Stokes shift (Figure 5a).

Within the cubic phase of  $Cs_2AgBiCl_6$ , the blue shift of STE emission is mainly attributed to the reduced lattice relaxation energy  $E_{LR}$  with the contracted bond lengths and unchanged

Br-Bi-Br and Br-Ag-Br bong angles, suggesting that the STE state of Cs<sub>2</sub>AgBiCl<sub>6</sub> tends to a metastable state due to the electron-phonon coupling decrease.<sup>45,49</sup> The  $E_{LR}$  is related to the fwhm ( $\Delta$ ) of STE emission,  $\Delta \propto \sqrt{2E_{\rm LR}k_{\rm B}T}$ , which indicates that the  $E_{\rm LR}$  decreases as pressure increases in the cubic phase.<sup>47</sup> The pressure effect of the activation energy barrier for self-trapping  $E_{\rm a,trap}$  and the potential barrier  $E_{\rm p,b}$ between adjacent STE state levels significantly affect the width and intensity of the emission band.<sup>45,46,50</sup> At ambient conditions, the carriers with constant lattice thermal energy surmount the activation barrier  $E_{a,trap}$  or  $E_{a,detrap}$  to realize the transition of exciton states from the free-exciton (FE) states to the STE states or from the STE states to the FE states. With increasing pressure, both the activation energy barrier for selftrapping  $E_{a,trap}$  and the potential barrier  $E_{p,b}$  gradually increase. The enhanced potential barrier  $E_{p,b}$  with an adiabatic potential energy surface that changes from initially smooth to sharp causes STE localization. Thus, the emission band that we observed narrows and increases in intensity at lower pressures. The enhanced activation energy barrier  $E_{a,trap}$  reduces FE with definite lattice thermal energy from the FE states into the STE states, thereby resulting in a continuous decrease in the emission intensity as pressure increases. The potential barrier  $E_{p,b}$  is more sensitive to pressure change than the activation energy barrier  $E_{a,trap}$ ; therefore, the STE first emission increases and then decreases with pressure. The overall STE evolution mechanisms are illustrated in Figure 5. The suppression effect of pressure on emission also contributes to the disappearance of the emission band, which is common in 3D metal halide perovskites.<sup>36</sup> The red shift of the band gap is due to the homogeneous reduction in octahedral volume, where Ag-Cl and Bi-Cl bond contraction enhances metal halide orbital coupling and electronic band dispersion.<sup>26</sup> For the tetragonal phase of Cs<sub>2</sub>AgBiCl<sub>6</sub>, the rotation and distortion of AgCl<sub>6</sub> and BiCl<sub>6</sub> octahedra increase the electron-phonon coupling strength, leading to emission red shift and broadening from about 5 to 7.5 GPa. Significantly enhancing electron-phonon coupling by increasing structural distortion has been confirmed in our recent low-dimensional metal halide perovskite studies.<sup>51,52</sup> Here, the rotation and distortion of AgCl<sub>6</sub> and BiCl<sub>6</sub> octahedra can decrease orbital coupling and electronic band dispersion and consequently decrease the band gap. The sharp increase of the band gap during the phase transition is likely dominated by the remarkable octahedra rotation from 5 to 7 GPa. The re-emergence of a decrease with further compression suggests that Ag–Cl and Bi–Cl bond contractions bring about a stronger effect than octahedra rotation and distortion. With the increase in structural distortion, these two competing effects on the electronic landscape reach a balance, resulting in a nearly unchanged band gap over a large pressure range.

In summary, we studied the structural, optical, and electrical property changes in metal halide double perovskite Cs<sub>2</sub>AgBiCl<sub>6</sub> upon compression up to 31 GPa at room temperature. The broad emission with a large Stokes shift is ascribed to exciton self-trapping due to strong electron-phonon coupling. Within the cubic phase, an abnormal PL blue shift accompanied by an absorption edge red shift occurs under pressure, which originates from the decreased lattice relaxation energy  $E_{LR}$ and increased metal halide orbital overlap upon Ag-Cl and Bi-Cl bond contraction, respectively. Octahedral rotation along the *c* axis leads to a structural phase transition from *Fm*-3m to I4/m, corresponding to a PL red shift and absorption edge blue shift. Strong electron-phonon coupling via Fröhlich interactions in Cs2AgBiCl6 is confirmed by the large Huang-Rhys parameter of 18.1. Lattice compression can effectively reduce the electron-phonon coupling strength in the cubic phase, which is our first discovery in the high-pressure studies of the 3D halide perovskites. Maintaining a highly symmetric cubic structure is crucial for achieving simultaneous band gap narrowing, electron-phonon coupling reduction, and ionic suppression under pressure. This work provides opportunities for the modulation and tuning of optical and electric transport properties of halide double perovskites and demonstrates the need for further exploration for improving their photovoltaic and optoelectronic performance by introducing lattice strain and chemical or mechanical pressure under practical conditions.

## ASSOCIATED CONTENT

#### **S** Supporting Information

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Experimental details and additional figures and tables, showing absorption spectra, PL spectra, TRPL spectra, a pressure dependence plot, chromaticity coordinates, PL peak locations, synchrotron XRD patterns, inorganic frameworks, the evolution of cell parameters and volumes upon compression, Raman spectra, electrical resistance, evolution of the Huang–Rhys parameters, and SEM images (PDF)

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### Notes

The authors declare no competing financial interest.

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